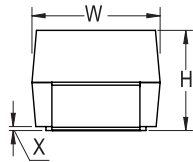


## T493X476K035BT6310

T493 HRA, Tantalum, MnO<sub>2</sub> Tantalum, HRA, 47 uF, 10%, 35 VDC, SMD, MnO<sub>2</sub>, Molded, High Reliability, B (0.1%/1000 Hrs), 250 mOhms, 7343, 4.3 mm, 1.3 mm

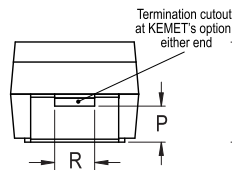
CATHODE (-) END VIEW



SIDE VIEW



ANODE (+) END VIEW



BOTTOM VIEW



Click [here](#) for the 3D model.

### General Information

Series	T493 HRA
Dielectric	MnO <sub>2</sub> Tantalum
Style	SMD Chip
Description	SMD, MnO <sub>2</sub> , Molded, High Reliability
Features	High Reliability
RoHS	Yes
Termination	Tin
AEC-Q200	No
Typical Component Weight	654.04 mg

### Specifications

Capacitance	47 uF
Tolerance	10%
Voltage DC	35 VDC (85C), 23.45 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	0.25 Ohms (100kHz 25C)
Ripple Current	812 mA (rms, 100kHz 25C)
Leakage Current	16.5 uA (5min 25°C)
Testing and Reliability	10 Cycles Surge Current Testing At -55C And +85C After Weibull

### Dimensions

L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	4mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.8mm MIN
B	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
P	1.7mm REF
R	1mm REF
X	0.1mm +/-0.1mm REF

### Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.